HZ-P Series

Silicon Epitaxial Planar Zener Diodes
for Voltage Controller & Voltage Limitter

HITACHI

ADE-208-123D (Z)

Rev.4
Sep. 2000

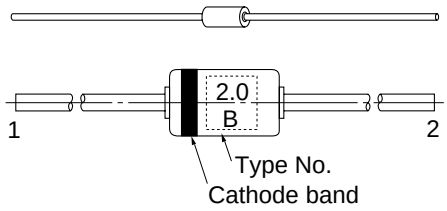
Features

- Wide spectrum from 1.88V through 40V of zener voltage provide flexible application.
- Glass package DO-41 structure ensures high reliability.

Ordering Information

Type No.	Mark	Package Code
HZ-P Series	Type No.	DO-41

Outline



1. Cathode
2. Anode

Hitachi semiconductor

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Power dissipation	Pd	0.8	W
Junction temperature	Tj	175	°C
Storage temperature	Tstg	–55 to +175	°C

Electrical Characteristics

(Ta = 25°C)

		Zener Voltage			Reverese Current		Dynamic Resistance	
		V_Z (V)*[1]		Test Condition	I_R (µA)	Test Condition	r_d (Ω)	Test Condition
Type	Grade	Min	Max	I_Z (mA)	Max	V_R (V)	Max	I_Z (mA)
HZ2.0	BP	1.88	2.12	40	200	0.5	25	40
	CP	2.00	2.24					
HZ2.2	BP	2.08	2.33	40	200	0.7	20	40
	CP	2.20	2.45					
HZ2.4	BP	2.28	2.56	40	200	1.0	15	40
	CP	2.40	2.70					
HZ2.7	BP	2.5	2.9	40	200	1.0	15	40
	CP	2.7	3.1					
HZ3.0	BP	2.8	3.2	40	100	1.0	15	40
	CP	3.0	3.4					
HZ3.3	BP	3.1	3.5	40	80	1.0	15	40
	CP	3.3	3.7					
HZ3.6	BP	3.4	3.8	40	60	1.0	15	40
	CP	3.6	4.0					
HZ3.9	BP	3.7	4.1	40	40	1.0	15	40
	CP	3.9	4.4					
HZ4.3	BP	4.0	4.5	40	20	1.0	15	40
	CP	4.3	4.8					
HZ4.7	BP	4.4	4.9	40	20	1.0	10	40
	CP	4.7	5.2					

Note: 1. Tested with DC.

Electrical Characteristics (cont)

(Ta = 25°C)

		Zener Voltage			Reverese Current		Dynamic Resistance	
		V_Z (V)*[1]		Test Condition	I_R (µA)	Test Condition	r_d (Ω)	Test Condition
Type	Grade	Min	Max	I_Z (mA)	Max	V_R (V)	Max	I_Z (mA)
HZ5.1	BP	4.8	5.4	40	20	1.0	8	40
	CP	5.1	5.7					
HZ5.6	BP	5.3	6.0	40	20	1.5	8	40
	CP	5.6	6.3					
HZ6.2	BP	5.8	6.6	40	20	3.0	6	40
	CP	6.2	7.0					
HZ6.8	BP	6.4	7.2	40	20	3.5	6	40
	CP	6.8	7.7					
HZ7.5	BP	7.0	7.9	40	20	4.0	4	40
	CP	7.5	8.4					
HZ8.2	BP	7.7	8.7	40	20	5.0	4	40
	CP	8.2	9.3					
HZ9.1	BP	8.5	9.6	40	20	6.0	6	40
	CP	9.1	10.2					
HZ10	BP	9.4	10.6	40	10	7.0	6	40
	CP	10.0	11.2					
HZ11	BP	10.4	11.6	20	10	8.0	8	20
	CP	11.0	12.3					
HZ12	BP	11.4	12.6	20	10	9.0	8	20
	CP	12.0	13.5					
HZ13	BP	12.4	14.1	20	10	10.0	10	20
	CP	13.3	15.0					
HZ15	BP	13.8	15.6	20	10	11.0	10	20
	CP	14.7	16.5					
HZ16	BP	15.3	17.1	20	10	12.0	12	20
	CP	16.2	18.3					
HZ18	BP	16.8	19.1	20	10	13.0	12	20
	CP	18.0	20.3					
HZ20	BP	18.8	21.2	20	10	15.0	14	20
	CP	20.0	22.4					

Note: 1. Tested with DC.

Electrical Characteristics (cont)

(Ta = 25°C)

		Zener Voltage			Reverese Current		Dynamic Resistance	
		V_Z (V)*[1]		Test Condition	I_R (µA)	Test Condition	r_d (Ω)	Test Condition
Type	Grade	Min	Max	I_Z (mA)	Max	V_R (V)	Max	I_Z (mA)
HZ22	BP	20.8	23.3	10	10	17.0	14	10
	CP	22.0	24.5					
HZ24	BP	22.8	25.6	10	10	19.0	16	10
	CP	24.0	27.6					
HZ27	BP	25.1	28.9	10	10	21.0	16	10
	CP	27.0	30.8					
HZ30	BP	28.0	32.0	10	10	23.0	18	10
	CP	30.0	34.0					
HZ33	BP	31.0	35.0	10	10	25.0	18	10
	CP	33.0	37.0					
HZ36	BP	34.0	38.0	10	10	27.0	20	10
	CP	36.0	40.0					

Notes: 1. Tested with DC.
2. Type No. is as follows; HZ2.0BP, HZ2.0CP, • • • HZ36BP, HZ36CP.

Main Characteristic

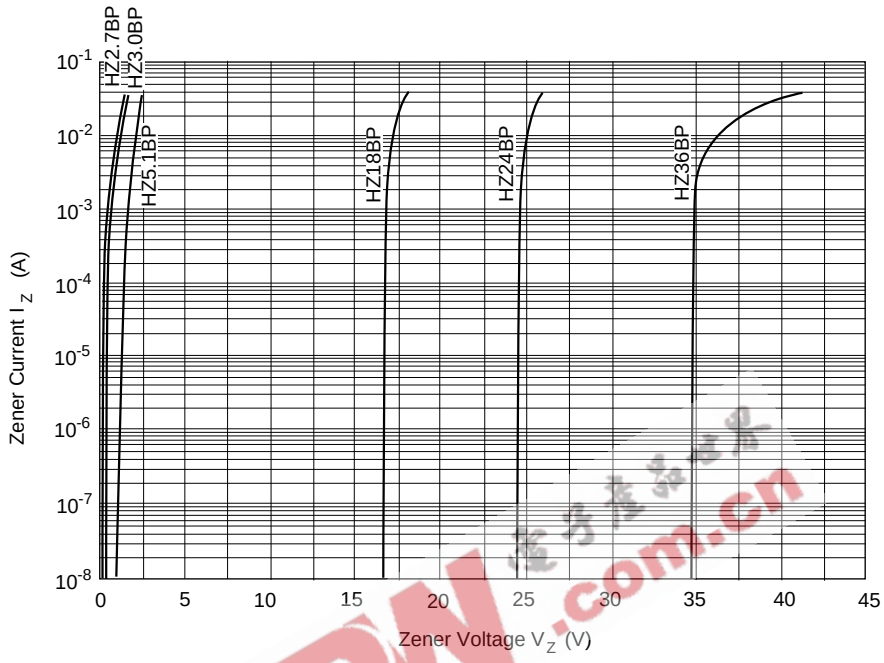


Fig.1 Zener current Vs. Zener voltage

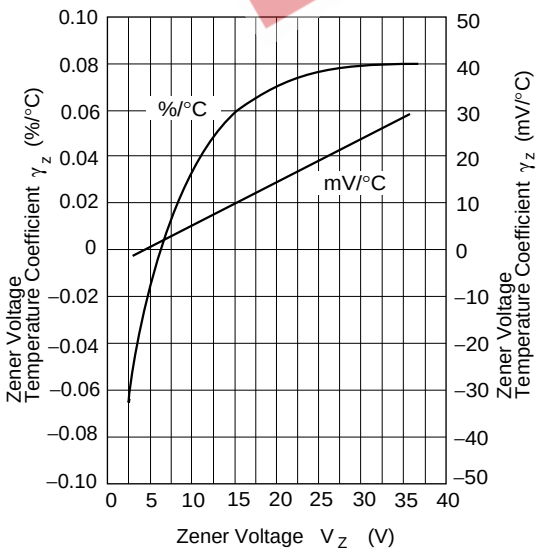


Fig.2 Temperature Coefficient Vs. Zener voltage

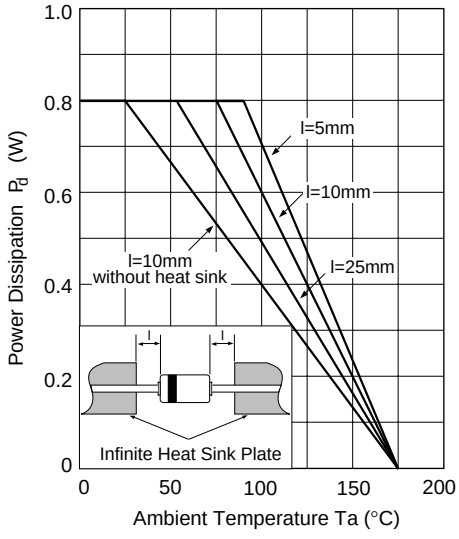


Fig.3 Power Dissipation Vs. Ambient Temperature

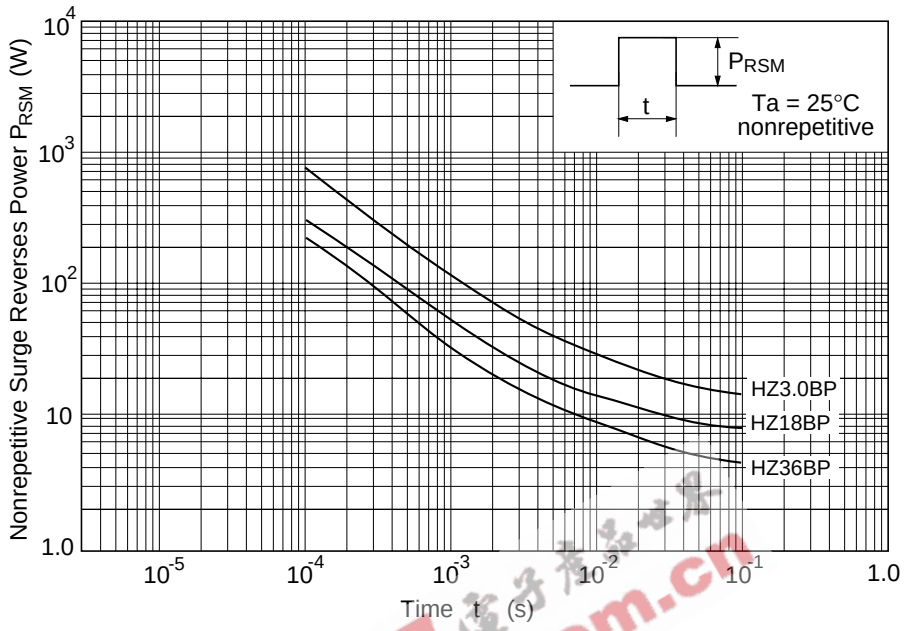


Fig.4 Surge Reverse Power Ratings (Reference Data)

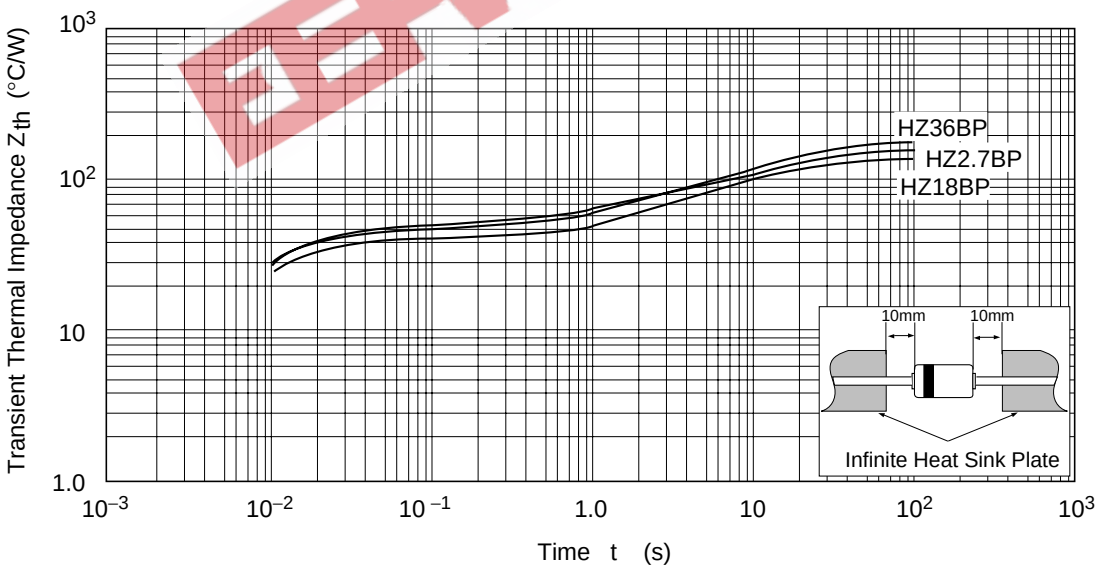
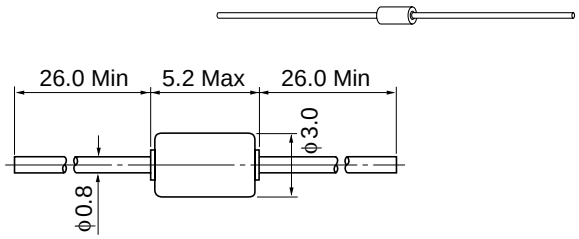


Fig.5 Transient Thermal Impedance

Package Dimensions

Unit: mm



Hitachi Code	DO-41
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.38 g

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